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U3B-E3, U3C-E3, U3D-E3

Vishay General Semiconductor

Surface Mount Ultrafast Plastic Rectifier



DO-214AB (SMC)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	3.0 A				
V _{RRM}	100 V, 150 V, 200 V				
I _{FSM}	100 A				
t _{rr}	20 ns				
V_F at I_F = 3.0 A	0.74 V				
T _J max.	150 °C				
Package	DO-214AB (SMC)				
Diode variations	Single die				

FEATURES

- Oxide planar chip junction
- Ultrafast recovery time
- · Low forward voltage, low power losses
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For us in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, automotive and telecommunication.

MECHANICAL DATA

Case: DO-214AB (SMC) Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER		SYMBOL	U3B	U3C	U3D	UNIT	
Device marking code			U3B	U3C	U3D		
Maximum repetitive peak reverse voltage		V _{RRM}	100	150	200	V	
Maximum average forward rectified current (fig. 1)	T _M = 134 °C	I _{F(AV)} ⁽¹⁾	2.0			A	
	T _M = 125 °C	I _{F(AV)} ⁽²⁾	3.0				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	100			A	
Operating junction and storage temperature range		T _J , T _{STG}	-55 to +150			°C	

Notes

⁽¹⁾ Free air, mounted on recommended copper pad area

⁽²⁾ Units mounted on PCB with 0.47" x 0.47" (12 mm x 12 mm) copper pad areas

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage	I _F = 3.0 A	T _A = 25 °C	V _F ⁽¹⁾	0.85	0.90	V	
		T _A = 100 °C		0.74	0.83		
Reverse current	Rated V _B	T _A = 25 °C	I _R ⁽²⁾	-	10	μA	
	naleu v _R	T _A = 100 °C		250	500		
Reverse recovery time	$I_{F} = 0.5 \text{ A}, I_{R} = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$	T _A = 25 °C	t _{rr}	-	20	ns	
	$ I_F = 3.0 \text{ A}, \text{ dI/dt} = 50 \text{ A/}\mu\text{s}, \\ V_R = 30 \text{ V}, \text{ I}_{rr} = 0.1 \text{ I}_{RM} $	T _A = 25 °C		25	30		
		T _A = 100 °C		35	50		
Storage charge	$\begin{array}{l} I_F=3.0 \text{ A, } dI/dt=50 \text{ A/}\mu\text{s,} \\ V_R=30 \text{ V, } I_{rr}=0.1 I_{RM} \end{array}$	T _A = 25 °C	Q _{rr}	9	15	nC	
		T _A = 100 °C		22	35		
Typical junction capacitance	4.0 V, 1 MHz		CJ	25	-	pF	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	DL U3B U3C U3D		UNIT	
Typical thermal resistance	R _{0JA} ⁽¹⁾	92			°C/W
	R _{0JM} ⁽¹⁾		10		0/10

Note

⁽¹⁾ Free air, mounted on recommended copper pad area. Thermal resistance $R_{\theta,A}$ - junction to ambient, $R_{\theta,JM}$ - junction to mount

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
U3D-E3/57T	0.239	57T	850	7" diameter plastic tape and reel		
U3D-E3/9AT	0.239	9AT	3500	13" diameter plastic tape and reel		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

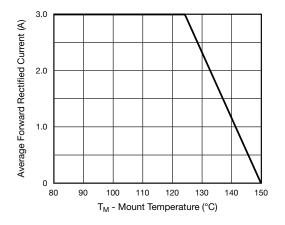


Fig. 1 - Maximum Forward Current Derating Curve

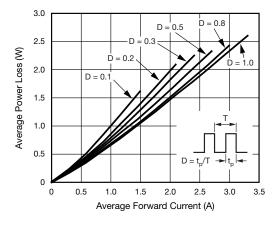


Fig. 2 - Forward Power Loss Characteristics

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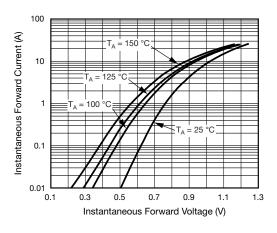


Fig. 3 - Typical Instantaneous Forward Characteristics

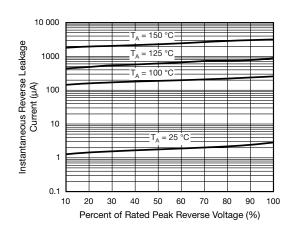
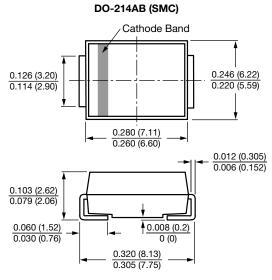


Fig. 4 - Typical Reverse Leakage Characteristics





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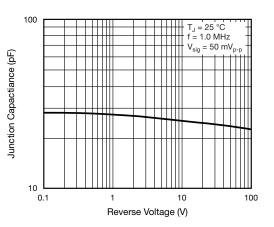


Fig. 5 - Typical Junction Capacitance

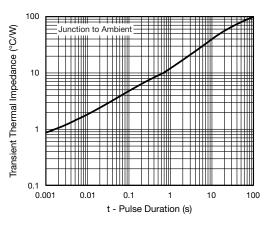
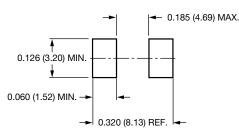


Fig. 6 - Typical Transient Thermal Impedance

Mounting Pad Layout







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